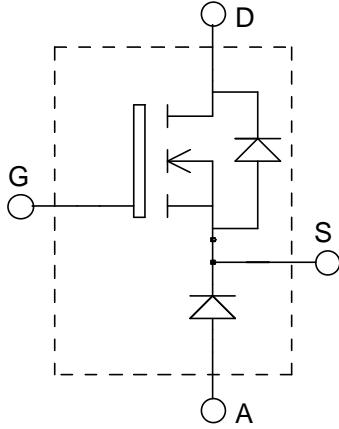


***ISOTOP[®] Buck chopper
MOSFET Power Module***

V_{DSS} = 500V
R_{DSon} = 65mΩ Max @ T_j = 25°C
I_D = 58A @ T_c = 25°C



Application

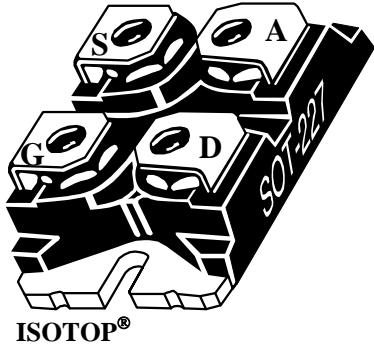
- AC and DC motor control
- Switched Mode Power Supplies

Features

- Power MOS 8™ MOSFETs
 - Low R_{DSon}
 - Low input and Miller capacitance
 - Low gate charge
 - Avalanche energy rated
 - Very rugged
- ISOTOP[®] Package (SOT-227)
- Very low stray inductance
- High level of integration

Benefits

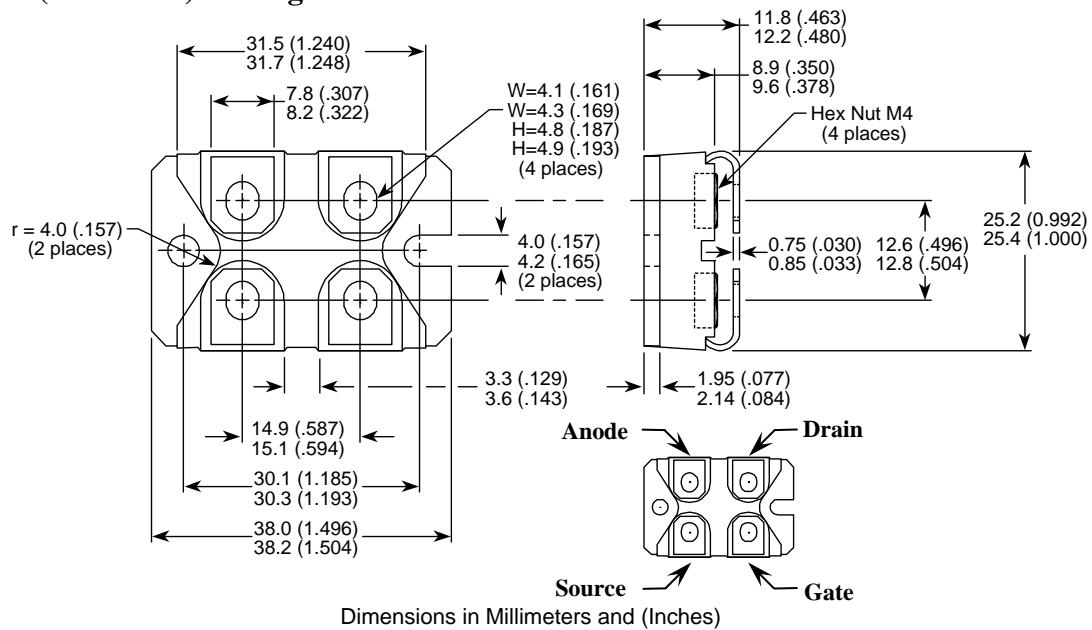
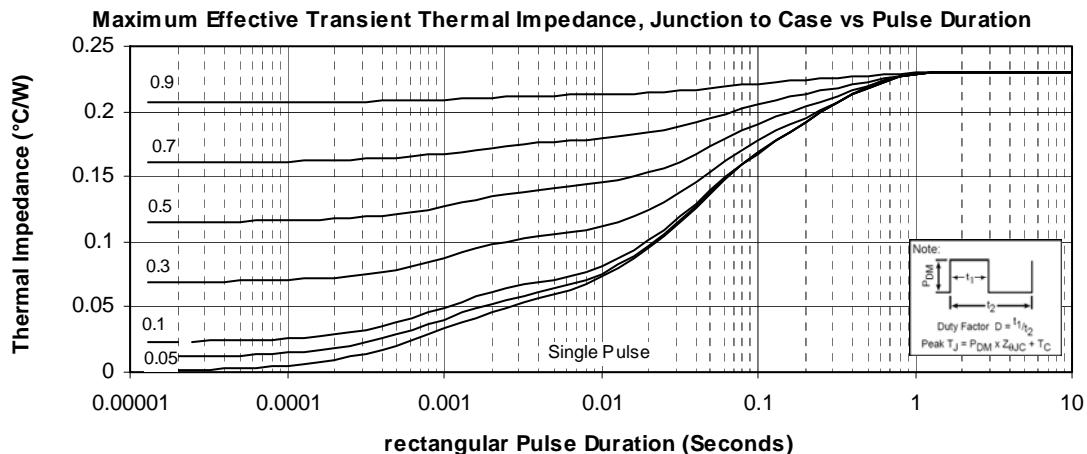
- Outstanding performance at high frequency operation
- Stable temperature behavior
- Very rugged
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Easy paralleling due to positive TC of VCEsat
- RoHS Compliant

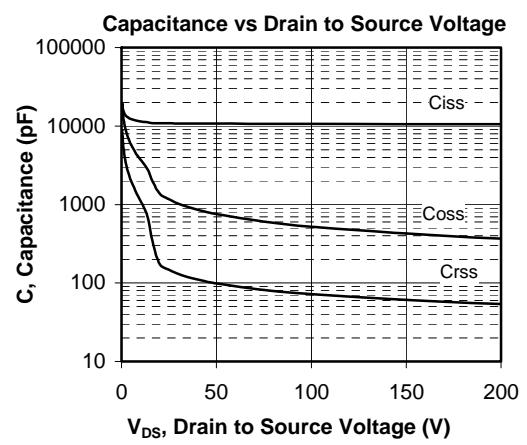
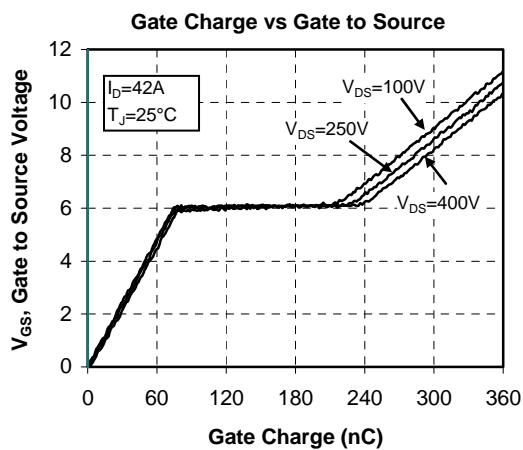
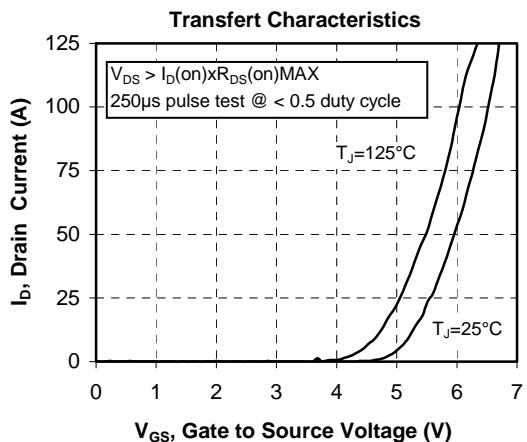
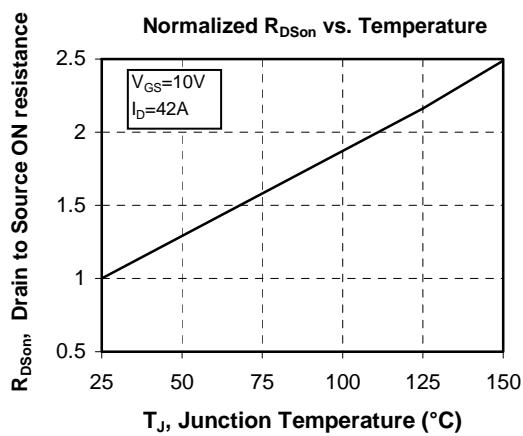
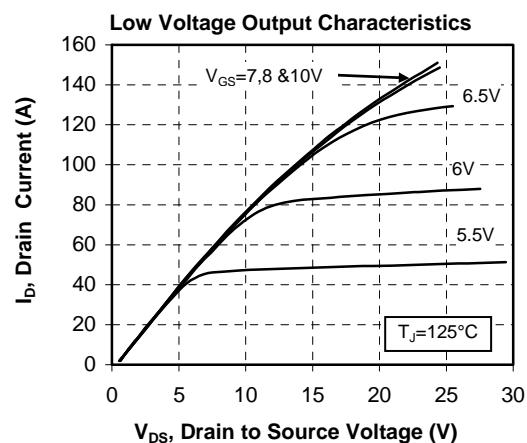
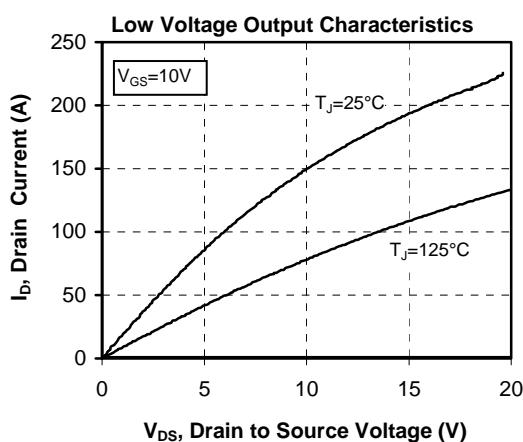


Absolute maximum ratings

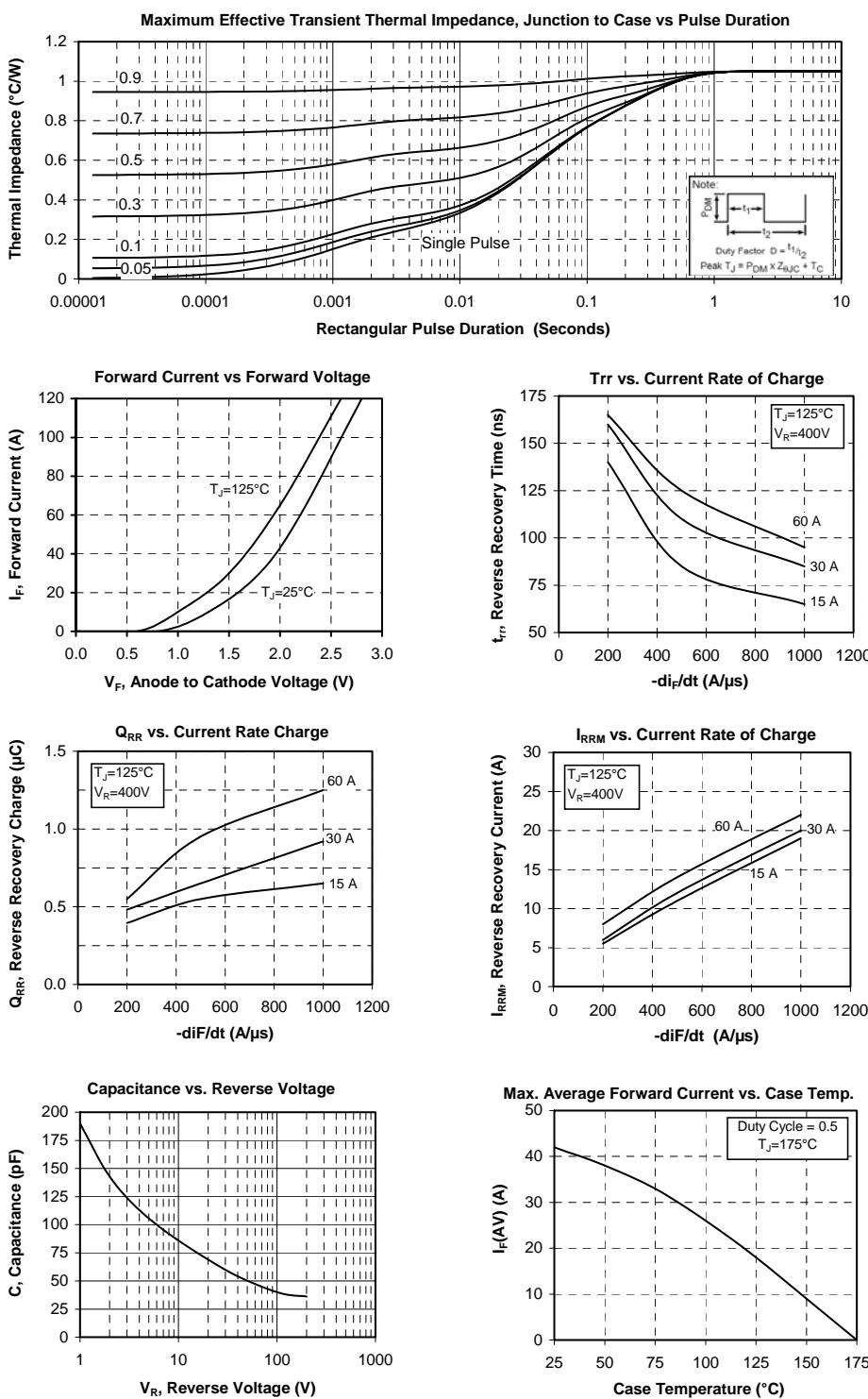
Symbol	Parameter	Max ratings	Unit
V _{DSS}	Drain - Source Breakdown Voltage	500	V
I _D	Continuous Drain Current	T _c = 25°C T _c = 80°C	58 43
I _{DM}	Pulsed Drain current		
V _{GS}	Gate - Source Voltage	±30	V
R _{DSon}	Drain - Source ON Resistance	65	mΩ
P _D	Maximum Power Dissipation	T _c = 25°C	W
I _{AR}	Avalanche current (repetitive and non repetitive)	42	A

 **CAUTION:** These Devices are sensitive to Electrostatic Discharge. Proper Handing Procedures Should Be Followed. See application note APT0502 on www.microsemi.com

SOT-227 (ISOTOP®) Package Outline

Typical Mosfet Performance Curve




Typical Diode Performance Curve



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Microsemi reserves the right to change, without notice, the specifications and information contained herein

Microsemi's products are covered by one or more of U.S patents 4,895,810 5,045,903 5,089,434 5,182,234 5,019,522 5,262,336 6,503,786 5,256,583 4,748,103 5,283,202 5,231,474 5,434,095 5,528,058 and foreign patents. U.S and Foreign patents pending. All Rights Reserved.